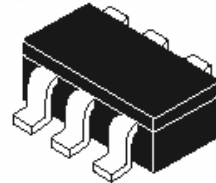




STB7101

0.9/1.9GHz BROAD BAND PRE-POWER AMPLIFIER

- OPERATING FREQUENCY 900-1900MHz
- OUTPUT POWER 9.8dBm typ. @ 900MHz
7.5dBm typ. @ 1900MHz
- POWER GAIN $G_P = 20.3\text{dB}$ typ. @ 900MHz
 $G_P = 20.5\text{dB}$ typ. @ 1900MHz



SOT323-6L (SC70)

ORDER CODE
STB7101

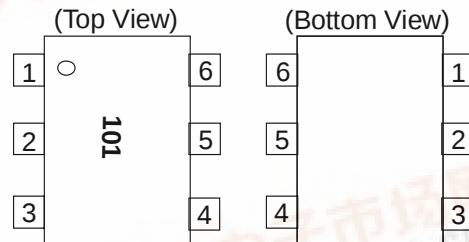
BRANDING
101

APPLICATIONS

PA driver for cellular applications

DESCRIPTION

The STB7101, designed for cellular applications (0.9/1.9GHz), uses a 20 GHz F_T silicon bipolar process. This IC is a wide range amplifier operating from 900MHz to 1900MHz, in the overall frequencies range the gain flatness is less than 1 dB. The STB7101 is housed in a very small SMD package SOT323-6L.



PIN CONNECTION

Pin No.	Pin Name
1	GND
2	GND
3	INPUT
4	VCC
5	GND
6	OUTPUT

ABSOLUTE MAXIMUM RATINGS

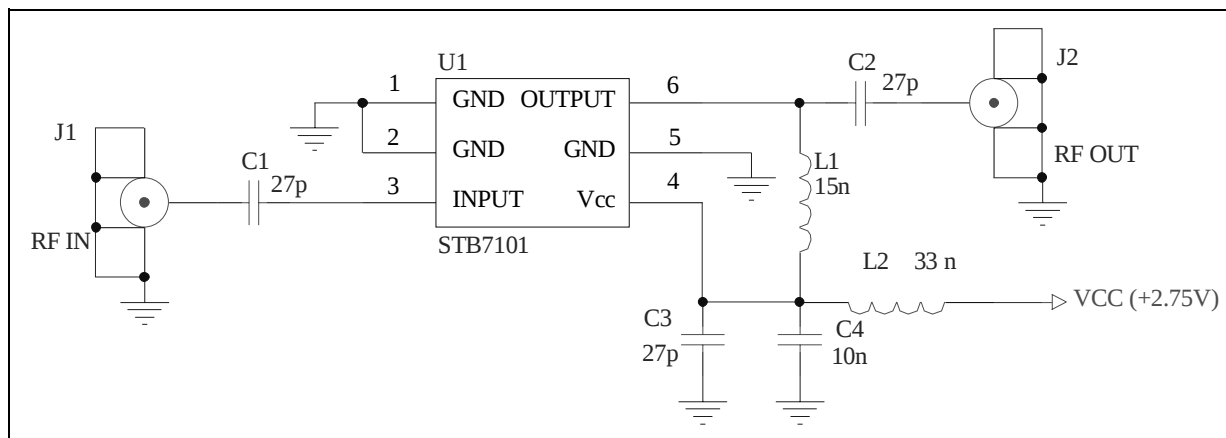
Symbol	Parameter	Conditions	Value	Unit
V_{CC}	Supply voltage	$T_a = +25^\circ\text{C}$, pin 4 and 6	4.5	V
T_{stg}	Storage temperature		-55 to +150	$^\circ\text{C}$
T_a	Operating ambient temperature		-40 to +85	$^\circ\text{C}$
P_{in}	Input power	$T_a = +25^\circ\text{C}$	10	dBm

STB7101

ELECTRICAL CHARACTERISTICS ($T_a = +25^{\circ}\text{C}$, $V_{cc} = 2.75\text{V}$, $Z_L = Z_S = 50\Omega$, unless otherwise specified)

Symbol	Parameter	Test Conditions	Min.	Typ.	Max.	Unit
V_{cc}	Supply voltage		2.6	2.75	3.3	V
I_{cc}	Circuit current	No signal		28		mA
G_p	Power Gain	$f = 0.9\text{GHz}$ $f = 1.9\text{GHz}$		20.3 20.5		dB
NF	Noise figure	$f = 0.9\text{GHz}$ $f = 1.9\text{GHz}$		5 4.5		dB
$P_{1\text{dB}}$	Output 1dB Compr. Power	$f = 0.9\text{GHz}$ $f = 1.9\text{GHz}$		9.8 7.5		dBm
RL_{IN}	Input return loss	$f = 0.9\text{GHz}$ $f = 1.9\text{GHz}$		8 6.2		dB
RL_{OUT}	Output Return loss	$f = 0.9\text{GHz}$ $f = 1.9\text{GHz}$		9.7 9.7		dB
S_{12}	Isolation	$f = 0.9\text{GHz}$ $f = 1.9\text{GHz}$		-34 -33		dB
$P_o(\text{Sat})$	Saturated output power level	$f = 0.9\text{GHz}$ $f = 1.9\text{GHz}$		11.3 9.7		dBm
OIP3	Output Third Order Intercept	$f = 0.9\text{GHz}$ $f = 1.9\text{GHz}$		16.5 14.9		dBm

TYPICAL EVALUATION CIRCUIT

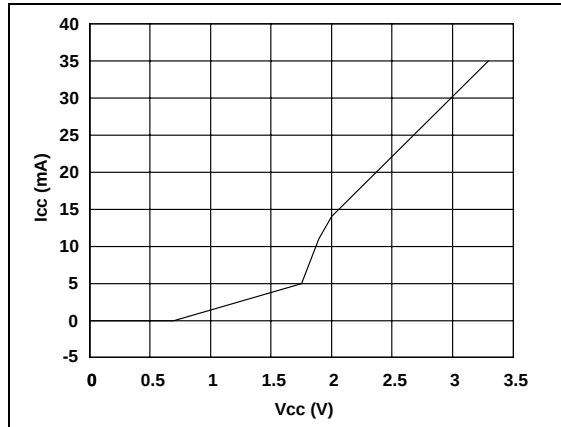


Evaluation circuit components

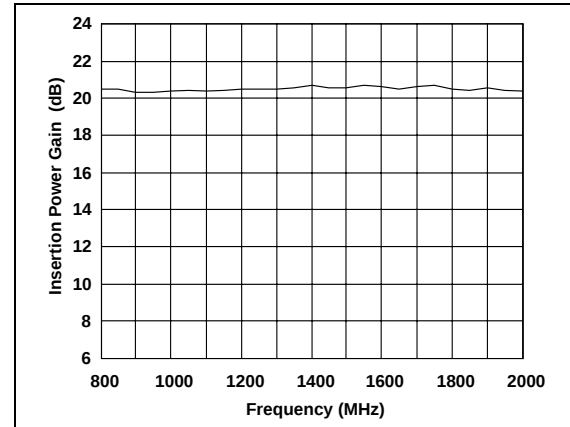
$C1 = C2 = C3 = 27\text{pF}$
$C4 = 10\text{nF}$
$L1 = 15\text{nH}$
$L2 = 33\text{nH}$

TYPICAL PERFORMANCE ($T_a = +25\text{ }^{\circ}\text{C}$, $V_{cc} = 2.75\text{V}$, unless otherwise specified)

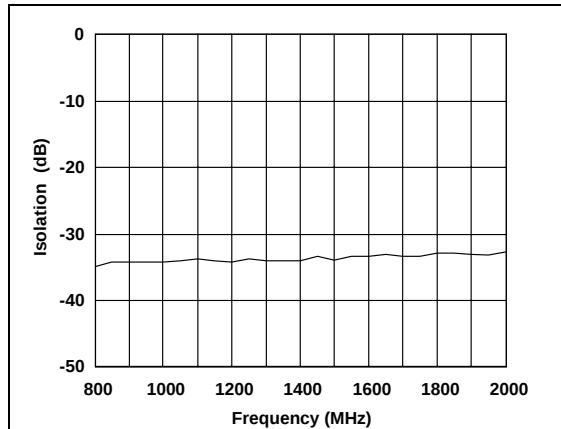
Circuit Current versus Supply Voltage



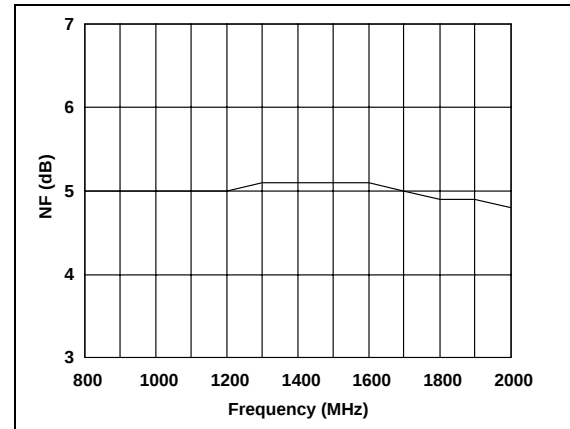
Insertion Power Gain versus Frequency



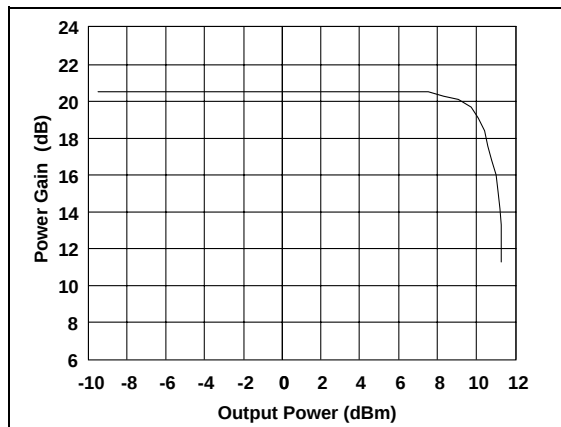
Isolation versus Frequency



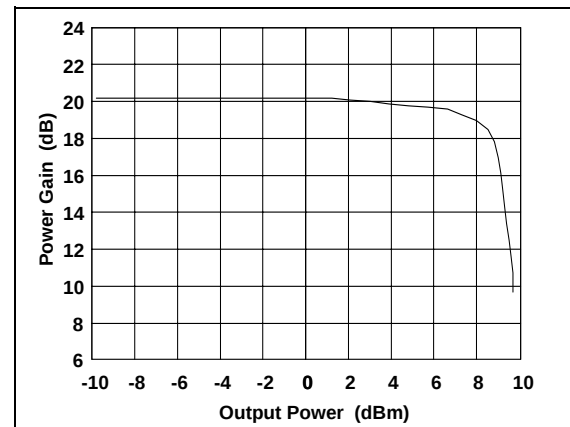
Noise Figure versus Frequency



Power Gain versus Output Power @ 900 MHz

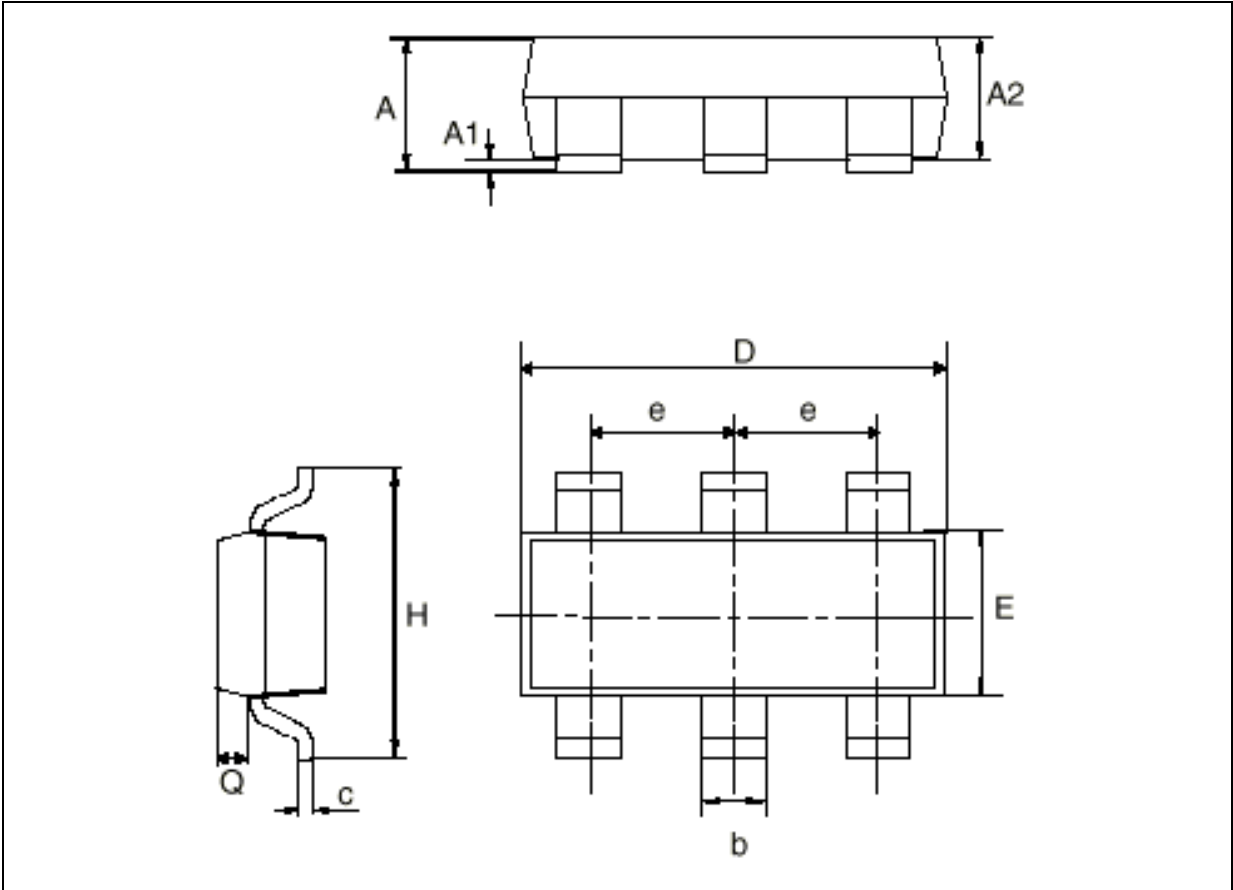


Power Gain versus Output Power @ 1900 MHz



SOT323-6L MECHANICAL DATA

DIM.	mm			Inch		
	MIN.	TYP.	MAX	MIN.	TYP.	MAX
A	0.8		1.1	0.031		0.043
A1	0		0.1	0		0.004
A2	0.8		1	0.0031		0.039
b	0.15		0.3	0.006		0.012
c	0.1		0.18	0.004		0.007
D	1.8		2.2	0.071		0.088
E	1.15		1.35	0.045		0.59
e		0.65			0.025	
H	1.8		2.4	0.071		0.094
Q	0.1		0.4	0.004		0.016



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